Thyristor/Diode Modules

V_{RRM} / V_{DRM} 800 to 1600V
I_{TAV} 60Amp

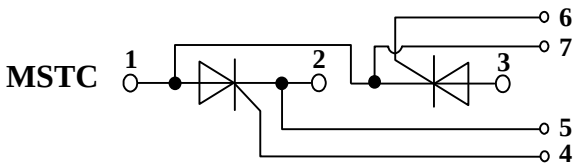
Applications

- Power Converters
- Lighting Control
- DC Motor Control and Drives
- Heat and temperature control

Features

- International standard package
- High Surge Capability
- Glass passivated chip
- Simple Mounting
- Heat transfer through aluminum oxide DCB ceramic isolated metal baseplate

Circuit



Module Type

TYPE	V_{RRM}	V_{RSM}
MSTC60-08 MSTC60-12 MSTC60-16	800V 1200V 1600V	900V 1300V 1700V

Maximum Ratings

Symbol	Conditions	Values	Units
I_{TAV}	Sine 180°;Tc=85℃	60	A
I_{TSM}	T_{VJ}=45℃ t=10ms, sine T_{VJ}=125℃ t=10ms, sine	1500 1250	A
i^2t	T_{VJ}=45℃ t=10ms, sine T_{VJ}=125℃ t=10ms, sine	11000 8000	A2s
Visol	a.c.50HZ;r.m.s.;1min	3000	V
Tvj		-40 to 125	℃
Tstg		-40 to 125	℃
Mt	To terminals(M5)	3±15%	Nm
Ms	To heatsink(M6)	5±15%	Nm
di/dt	T_{VJ}= T_{VJM} , 2/3V_{DRM} ,I_G =500mA Tr<0.5us,tp>6us	150	A/us
dv/dt	T_J= T_{VJM} ,2/3V_{DRM}, linear voltage rise	1000	V/us
a	Maximum allowable acceleration	50	m/s^2
Weight	Module(Approximately)	100	g

Thermal Characteristics

Symbol	Conditions	Values	Units
Rth(j-c)	Cont.;per thyristor / per module	0.57/0.29	℃/W
Rth(c-s)	per thyristor / per module	0.2/0.1	℃/W

Electrical Characteristics

Symbol	Conditions	Values			Units
		Min.	Typ.	Max.	
V_{TM}	T=25℃ I_{TM} =200A			1.65	V
I_{RRM}/I_{DRM}	T_{VJ} =T_{VJM} ,V_R=V_{RRM} ,V_D=V_{DRM}			15	mA
V_{TO}	For power-loss calculations only (T_{VJ} =125℃)			0.9	V
r_T	T_{VJ} =T_{VJM}			3.5	mΩ
V_{GT}	T_{VJ} =25℃ , V_D =6V			3.0	V
I_{GT}	T_{VJ} =25℃ , V_D =6V			150	mA
V_{GD}	T_{VJ} =125℃ , V_D =2/3V_{DRM}			0.25	V
I_{GD}	T_{VJ} =125℃ , V_D =2/3V_{DRM}			6	mA
I_L	T_{VJ} =25℃ , R_G = 33 Ω		300	600	mA
I_H	T_{VJ} =25℃ , V_D =6V		150	250	mA
tgd	T_{VJ} =25℃, I_G=1A, di_G/dt=1A/us		1		us
tq	T_{VJ} =T_{VJM}		80		us

Performance Curves

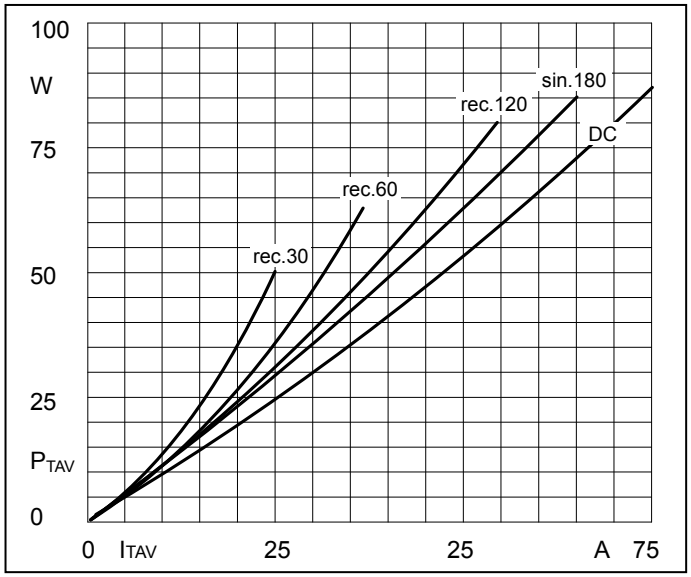


Fig1. Power dissipation

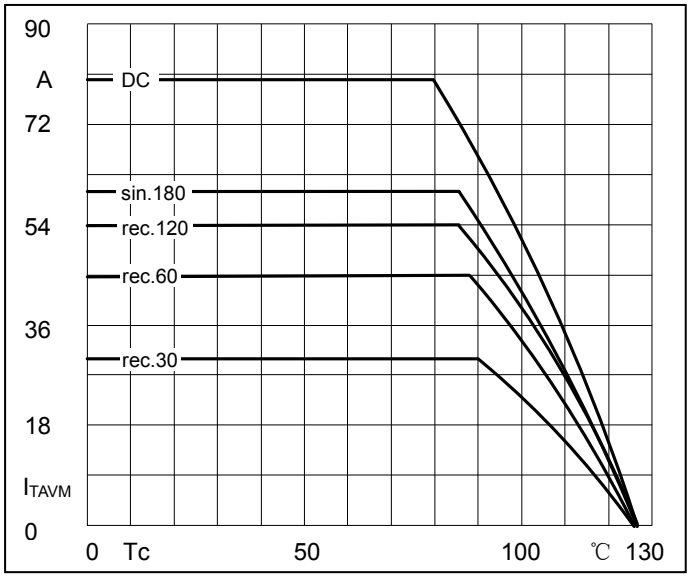


Fig2.Forward Current Derating Curve

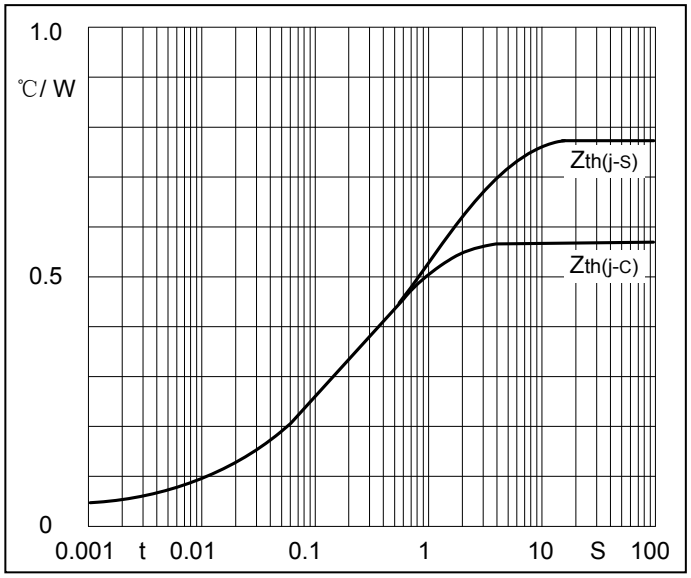


Fig3. Transient thermal impedance

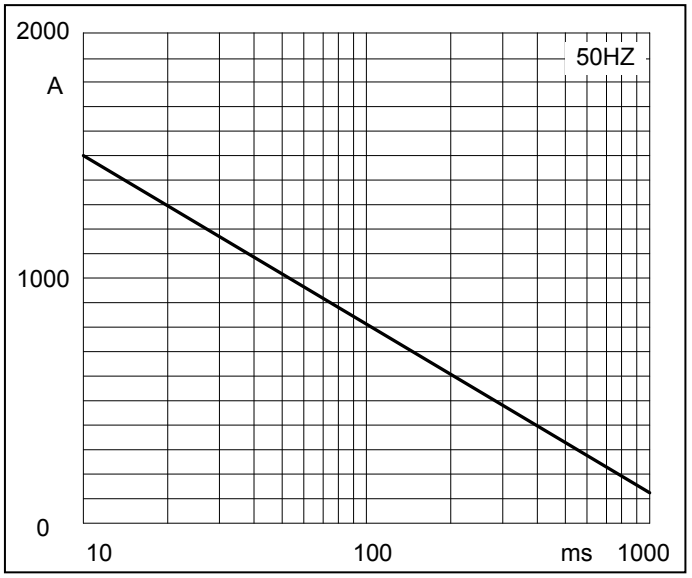


Fig4. Max Non-Repetitive Forward Surge Current

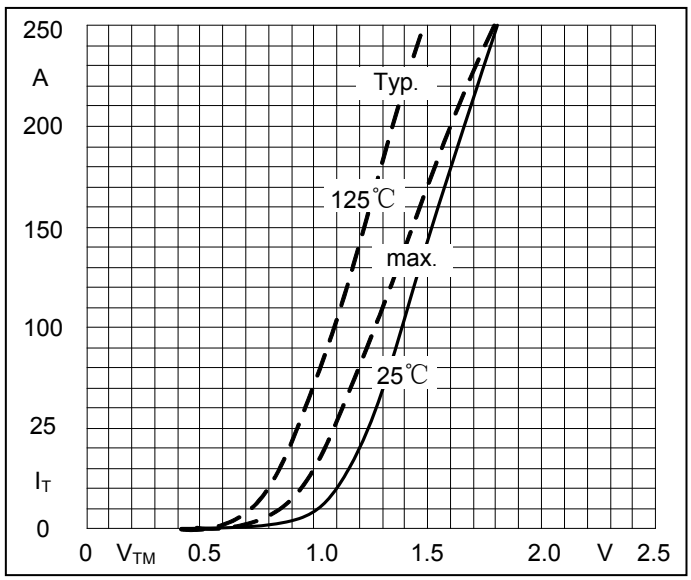


Fig5. Forward Characteristics

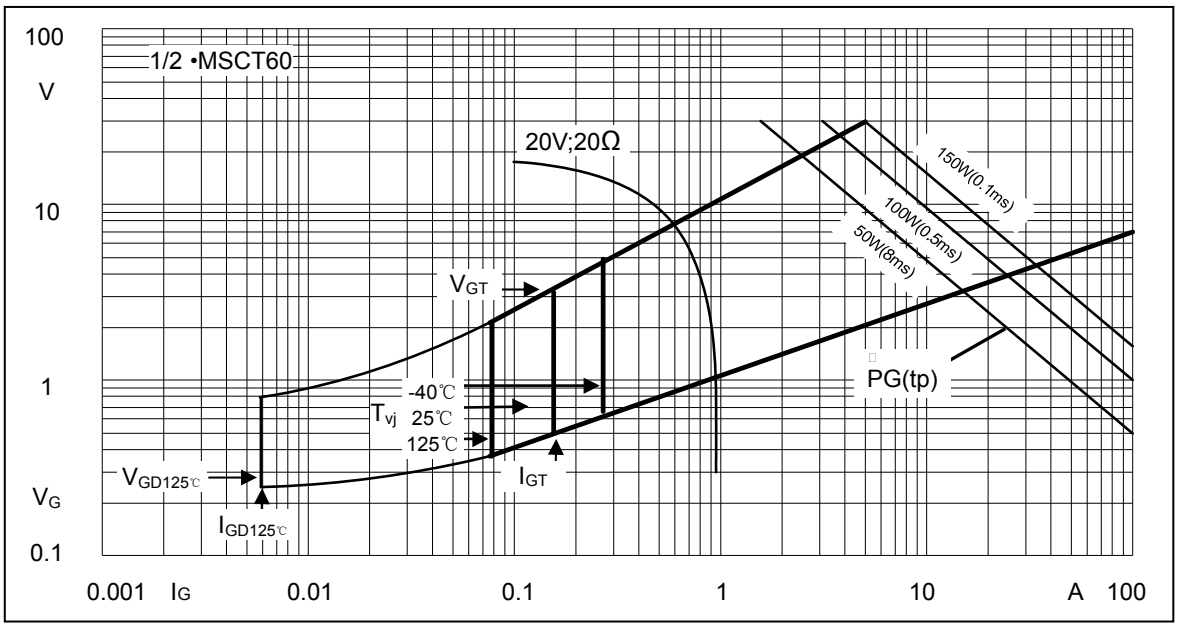
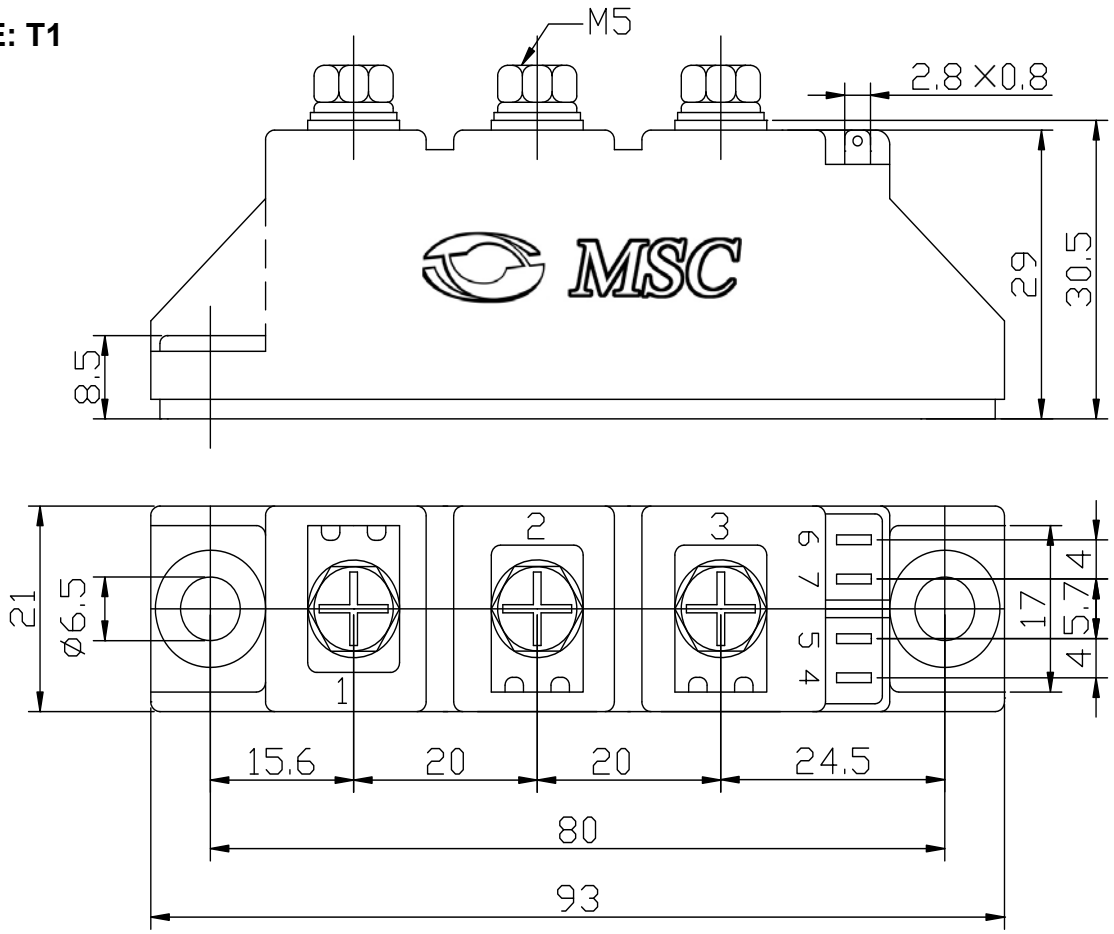


Fig6. Gate trigger Characteristics

Package Outline Information

CASE: T1



Dimensions in mm

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